



PATENT 2185-0578P

## IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant:

Yoshinobu ONO et al.

Conf.:

3053

Appl. No.:

09/977,375

Group:

281İ

Filed:

October 16, 2001

Examiner: J. Im

For:

3-5 GROUP COMPOUND SEMICONDUCTOR AND

LIGHT-EMITTING ELEMENT

AMENDMENT UNDER 37 C.F.R. § 1.111

Assistant Commissioner for Patents Washington, DC 20231

January 21, 2003 (Tuesday after Holiday)

Sir:

In reply to the Examiner's Office Action dated July 18, 2002, the period for response having been extended three (3) months to January 18, 2003, the following amendments and remarks are respectfully submitted in connection with the above-identified application.

## IN THE SPECIFICATION:

Please replace the paragraph beginning on page 1, line 7, with the following rewritten paragraph:

--Compound semiconductors of this kind have a laminated

structure of epitaxial crystal layers of 3-5 group compound

semiconductor on a GaAs substrate, and for example, light emitting

elements, which are widely used, have a laminated structure 01/23/2003 CV0111 00000015 09977375

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